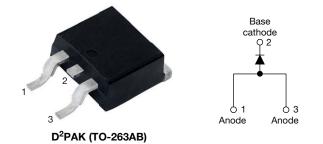
**Vishay Semiconductors** 

# High Voltage Surface Mount Input Rectifier Diode, 25 A



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| PRIMARY CHARACTERISTICS          |                               |  |  |  |  |
|----------------------------------|-------------------------------|--|--|--|--|
| I <sub>F(AV)</sub> 25 A          |                               |  |  |  |  |
| V <sub>R</sub>                   | 800 V, 1000 V, 1200 V         |  |  |  |  |
| V <sub>F</sub> at I <sub>F</sub> | 1.14 V                        |  |  |  |  |
| I <sub>FSM</sub>                 | 300 A                         |  |  |  |  |
| T <sub>j</sub> max.              | 150 °C                        |  |  |  |  |
| Package                          | D <sup>2</sup> PAK (TO-263AB) |  |  |  |  |
| Circuit configuration            | Single                        |  |  |  |  |

### FEATURES

- Glass passivated pellet chip junction
- Meets MSL level 1, per J-STD-020, LF maximum peak of 245 °C
- Designed and qualified according to JEDEC<sup>®</sup>-JESD 47
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

#### APPLICATIONS

- Input rectification
- Vishay switches and output rectifiers which are available in identical package outlines

### DESCRIPTION

The VS-25ETS..S-M3 rectifier High Voltage Series has been optimized for very low forward voltage drop, with moderate leakage. The glass passivation technology used has reliable operation up to 150 °C junction temperature.

| OUTPUT CURRENT IN TYPICAL APPLICATIONS  |    |    |   |  |  |  |
|---|----|----|---|--|--|--|
| APPLICATIONS SINGLE-PHASE BRIDGE THREE-PHASE BRIDGE UNITS   |    |    |   |  |  |  |
| Capacitive input filter $T_A = 55 \text{ °C}$ , $T_J = 125 \text{ °C}$<br>common heatsink of 1 °C/W | 20 | 23 | А |  |  |  |

| MAJOR RATINGS AND CHARACTERISTICS |                              |             |       |  |  |  |  |
|-----------------------------------|------------------------------|-------------|-------|--|--|--|--|
| SYMBOL                            | CHARACTERISTICS              | VALUES      | UNITS |  |  |  |  |
| I <sub>F(AV)</sub>                | Sinusoidal waveform          | 25          | A     |  |  |  |  |
| V <sub>RRM</sub>                  |                              | 800 to 1200 | V     |  |  |  |  |
| I <sub>FSM</sub>                  |                              | 300         | A     |  |  |  |  |
| V <sub>F</sub>                    | 10 A, T <sub>J</sub> = 25 °C | 1.0         | V     |  |  |  |  |
| TJ                                |                              | -40 to +150 | °C    |  |  |  |  |

| VOLTAGE RATINGS |   |  |                                  |  |  |  |  |
|-----------------|---|--|----------------------------------|--|--|--|--|
| PART NUMBER     | V <sub>RRM</sub> , MAXIMUM PEAK<br>REVERSE VOLTAGE<br>V | V <sub>RSM</sub> , MAXIMUM NON-REPETITIVE<br>PEAK REVERSE VOLTAGE<br>V | I <sub>RRM</sub> AT 150 °C<br>mA |  |  |  |  |
| VS-25ETS08S-M3  | 800   | 900  |                                  |  |  |  |  |
| VS-25ETS10S-M3  | 1000  | 1100   | 1                                |  |  |  |  |
| VS-25ETS12S-M3  | 1200  | 1300   |                                  |  |  |  |  |

| ABSOLUTE MAXIMUM RATINGS                               |                    |  |        |                  |  |  |
|--|--------------------|--|--------|------------------|--|--|
| PARAMETER  | SYMBOL             | TEST CONDITIONS  | VALUES | UNITS            |  |  |
| Maximum average forward current                        | I <sub>F(AV)</sub> | $T_C = 106 \ ^{\circ}C$ , 180° conduction half sine wave | 25     |                  |  |  |
| Maximum peak one cycle<br>non-repetitive surge current |                    | 10 ms sine pulse, rated V <sub>RRM</sub> applied         | 250    | А                |  |  |
|  | IFSM               | 10 ms sine pulse, no voltage reapplied                   | 300    |                  |  |  |
| Maximum I <sup>2</sup> t for fusing                    | l <sup>2</sup> t   | 10 ms sine pulse, rated V <sub>RRM</sub> applied         | 316    | A <sup>2</sup> s |  |  |
| Maximum i-t for fusing                                 | 1-1                | 10 ms sine pulse, no voltage reapplied                   | 442    | A-5              |  |  |
| Maximum I <sup>2</sup> $\sqrt{t}$ for fusing           | l²√t               | t = 0.1 ms to 10 ms, no voltage reapplied                | 4420   | A²√s             |  |  |

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| ELECTRICAL SPECIFICATIONS       |                    |                              |                         |      |       |  |  |
|---------------------------------|--------------------|------------------------------|-------------------------|------|-------|--|--|
| PARAMETER                       | SYMBOL             | TEST CONDITIONS VALUES       |                         |      | UNITS |  |  |
| Maximum forward voltage drop    | V <sub>FM</sub>    | 25 A, T <sub>J</sub> = 25 °C |                         | 1.14 | V     |  |  |
| Forward slope resistance        | r <sub>t</sub>     | T - 150 °C                   | 9.62                    | mΩ   |       |  |  |
| Threshold voltage               | V <sub>F(TO)</sub> | 1J = 150 C                   | T <sub>J</sub> = 150 °C |      |       |  |  |
| Maximum reverse leakage current | 1                  | T <sub>J</sub> = 25 °C       | $V_{B} = Rated V_{BBM}$ | 0.1  | m۸    |  |  |
| Maximum reverse leakage current | I <sub>RM</sub>    | T <sub>J</sub> = 150 °C      | VR = haleu VRRM         | 1.0  | mA    |  |  |

| THERMAL - MECHANICAL SPECIFICATIONS             |                         |                                   |  |             |            |  |
|---|-------------------------|-----------------------------------|--|-------------|------------|--|
| PARAMETER                                       |                         | SYMBOL                            | TEST CONDITIONS                          | VALUES      | UNITS      |  |
| Maximum junction and storage temperature range  | )                       | T <sub>J</sub> , T <sub>Stg</sub> |  | -40 to +150 | °C         |  |
| Maximum thermal resistance, junction to case    |                         | R <sub>thJC</sub>                 | DC operation                             | 0.9         |            |  |
| Maximum thermal resistance, junction to ambient |                         | R <sub>thJA</sub>                 |  | 62          | °C/W       |  |
| Typical thermal resistance, case to heatsink    |                         |                                   | Mounting surface, smooth, and greased    | 0.5         |            |  |
| Approximate weight                              |                         |                                   |  | 2           | g          |  |
| Approximate weight                              |                         |                                   |  | 0.07        | oz.        |  |
| Mounting torque                                 | minimum                 |                                   |  | 6 (5)       | kgf ⋅ cm   |  |
| Mounting torque                                 | Mounting torque maximum |                                   |  | 12 (10)     | (lbf ⋅ in) |  |
| Marking device                                  |                         |                                   |  | 25ET        | S08S       |  |
|   |                         |                                   | Case style D <sup>2</sup> PAK (TO-263AB) | 25ETS10S    |            |  |
|   |                         |                                   |  | 25ET        | S12S       |  |

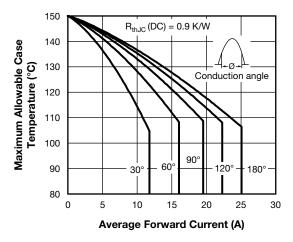


Fig. 1 - Current Rating Characteristics

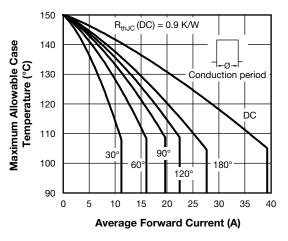
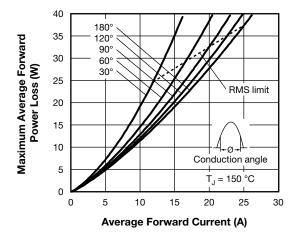


Fig. 2 - Current Rating Characteristics

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Fig. 3 - Forward Power Loss Characteristics

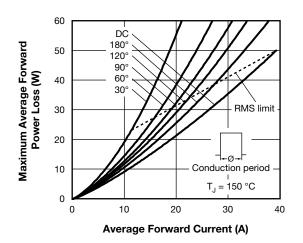


Fig. 4 - Forward Power Loss Characteristics

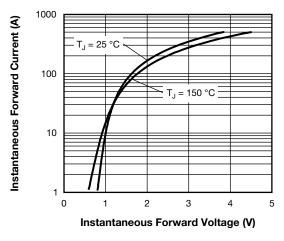
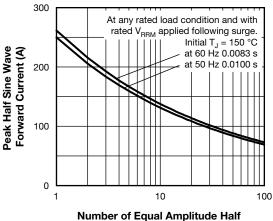


Fig. 7 - Forward Voltage Drop Characteristics



**Cycle Current Pulses (N)** 

Fig. 5 - Maximum Non-Repetitive Surge Current

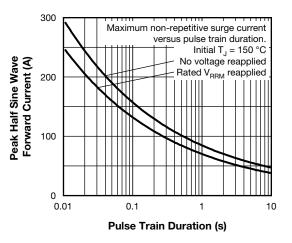
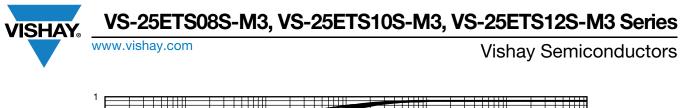


Fig. 6 - Maximum Non-Repetitive Surge Current

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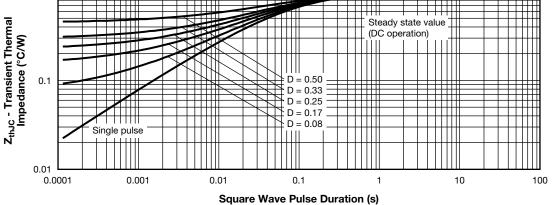


Fig. 8 - Thermal Impedance Z<sub>thJC</sub> Characteristics

### **ORDERING INFORMATION TABLE**

| Device code | VS-                             | 25                                       | Е   | т  | S  | 12       | S   | TRL                        | -M3            |
|-------------|---------------------------------|--|---|--|--|----------|-----|----------------------------|----------------|
|             | 1                               | 2  | 3   | 4  | 5  | 6        | 7   | 8                          | 9              |
|             | 1 -<br>2 -<br>3 -<br>4 -        | Cur<br>Circ<br>E<br>Pac                  | rrent rati<br>cuit conf<br>= single<br>kage:            | niconduo<br>ng (25 =<br>iguration<br>e<br>.K (TO-2 | = 25 A)<br>n   | oduct    |     |                            |                |
|             | 5 -<br>6 -<br>7 -<br>8 -<br>9 - | S<br>Voli<br>S =<br>• No<br>• TF<br>• TF | tage coo<br>surface<br>one = tu<br>RL = tap<br>RR = tap | lard reco<br>de x 100<br>mounta                    | i = V <sub>RRM</sub><br>ible<br>eel (left o<br>eel (righ | orientec | ed) | 08 = 8<br>10 = 1<br>12 = 1 | 000 V<br>200 V |

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| ORDERING INFORMATION (Example) |                   |                        |                         |  |  |  |  |  |
|--------------------------------|-------------------|------------------------|-------------------------|--|--|--|--|--|
| PREFERRED P/N                  | QUANTITY PER TUBE | MINIMUM ORDER QUANTITY | PACKAGING DESCRIPTION   |  |  |  |  |  |
| VS-25ETS08S-M3                 | 50                | 1000                   | Antistatic plastic tube |  |  |  |  |  |
| VS-25ETS08STRR-M3              | 800               | 800                    | 13" diameter reel       |  |  |  |  |  |
| VS-25ETS08STRL-M3              | 800               | 800                    | 13" diameter reel       |  |  |  |  |  |
| VS-25ETS10S-M3                 | 50                | 1000                   | Antistatic plastic tube |  |  |  |  |  |
| VS-25ETS10STRR-M3              | 800               | 800                    | 13" diameter reel       |  |  |  |  |  |
| VS-25ETS10STRL-M3              | 800               | 800                    | 13" diameter reel       |  |  |  |  |  |
| VS-25ETS12S-M3                 | 50                | 1000                   | Antistatic plastic tube |  |  |  |  |  |
| VS-25ETS12STRR-M3              | 800               | 800                    | 13" diameter reel       |  |  |  |  |  |
| VS-25ETS12STRL-M3              | 800               | 800                    | 13" diameter reel       |  |  |  |  |  |

| LINKS TO RELATED DOCUMENTS                 |                          |  |  |  |
|--|--------------------------|--|--|--|
| Dimensions <u>www.vishay.com/doc?96164</u> |                          |  |  |  |
| Part marking information                   | www.vishay.com/doc?95444 |  |  |  |
| Packaging information                      | www.vishay.com/doc?96424 |  |  |  |

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D<sup>2</sup>PAK

#### **DIMENSIONS** in millimeters and inches



| ota      | ted  | 90          | °C |
|----------|------|-------------|----|
| <u>S</u> | cale | <u>ə:</u> 8 | :1 |

| SYMBOL | MILLIM | ETERS | INC   | HES   | NOTES |  |
|--------|--------|-------|-------|-------|-------|--|
| STMBOL | MIN.   | MAX.  | MIN.  | MAX.  | NOTES |  |
| A      | 4.06   | 4.83  | 0.160 | 0.190 |       |  |
| A1     | 0.00   | 0.254 | 0.000 | 0.010 |       |  |
| b      | 0.51   | 0.99  | 0.020 | 0.039 |       |  |
| b1     | 0.51   | 0.89  | 0.020 | 0.035 | 4     |  |
| b2     | 1.14   | 1.78  | 0.045 | 0.070 |       |  |
| b3     | 1.14   | 1.73  | 0.045 | 0.068 | 4     |  |
| с      | 0.38   | 0.74  | 0.015 | 0.029 |       |  |
| c1     | 0.38   | 0.58  | 0.015 | 0.023 | 4     |  |
| c2     | 1.14   | 1.65  | 0.045 | 0.065 |       |  |
| D      | 8.51   | 9.65  | 0.335 | 0.380 | 2     |  |

| SYMBOL | MILLIMETERS |       | INCHES    |       | NOTES |
|--------|-------------|-------|-----------|-------|-------|
|        | MIN.        | MAX.  | MIN.      | MAX.  | NOTES |
| D1     | 6.86        | 8.00  | 0.270     | 0.315 | 3     |
| E      | 9.65        | 10.67 | 0.380     | 0.420 | 2, 3  |
| E1     | 7.90        | 8.80  | 0.311     | 0.346 | 3     |
| е      | 2.54 BSC    |       | 0.100 BSC |       |       |
| Н      | 14.61       | 15.88 | 0.575     | 0.625 |       |
| L      | 1.78        | 2.79  | 0.070     | 0.110 |       |
| L1     | -           | 1.65  | -         | 0.066 | 3     |
| L2     | 1.27        | 1.78  | 0.050     | 0.070 |       |
| L3     | 0.25 BSC    |       | 0.010 BSC |       |       |
| L4     | 4.78        | 5.28  | 0.188     | 0.208 |       |

#### Notes

<sup>(1)</sup> Dimensioning and tolerancing per ASME Y14.5 M-1994

(2) Dimension D and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outmost extremes of the plastic body

(3) Thermal pad contour optional within dimension E, L1, D1 and E1

<sup>(4)</sup> Dimension b1 and c1 apply to base metal only

(5) Datum A and B to be determined at datum plane H

(6) Controlling dimension: inches

<sup>(7)</sup> Outline conforms to JEDEC<sup>®</sup> outline TO-263AB

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